

# AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 400 A



| PRIMARY CHARACTERISTICS |                           |  |  |  |
|-------------------------|---------------------------|--|--|--|
| I <sub>F(AV)</sub>      | 400 A                     |  |  |  |
| V <sub>R</sub>          | 45 V                      |  |  |  |
| Package                 | AAP Gen 7 (TO-240AA)      |  |  |  |
| Circuit configuration   | Two diodes common cathode |  |  |  |

#### **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- · High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKCS400/045 Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |       |  |  |
|-----------------------------------|---|-------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS                               | VALUES      | UNITS |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 400         | A     |  |  |
| V <sub>RRM</sub>                  |   | 45          | V     |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                    | 29 000      | A     |  |  |
| V <sub>F</sub>                    | 200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.73        | V     |  |  |
| TJ                                | Range   | -55 to +150 | °C    |  |  |

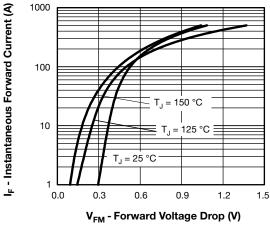
| VOLTAGE RATINGS                      |           |                 |       |  |  |
|--------------------------------------|-----------|-----------------|-------|--|--|
| PARAMETER                            | SYMBOL    | VS-VSKCS400/045 | UNITS |  |  |
| Maximum DC reverse voltage           | $V_{R}$   | 45              | V     |  |  |
| Maximum working peak reverse voltage | $V_{RWM}$ | 45              | V     |  |  |



| ABSOLUTE MAXIMUM RATINGS       |            |                    |   |   |        |       |
|--------------------------------|------------|--------------------|---|---|--------|-------|
| PARAMETER                      |            | SYMBOL             | TEST CONDITIONS   |   | VALUES | UNITS |
| Maximum average                | per module |                    |   |   | 400    |       |
| forward current                | per leg    | I <sub>F(AV)</sub> | 50 % duty cycle at T <sub>C</sub> = 91 °C, rectangular waveform   |   | 200    |       |
| Maximum peak one cycle         |            |                    | 5 μs sine or 3 μs rect. pulse   | Following any rated load condition and with | 29 000 | Α     |
| non-repetitive surge current   |            | I <sub>FSM</sub>   | 10 ms sine or 6 ms rect. pulse  | rated V <sub>RRM</sub> applied              | 3400   |       |
| Non-repetitive avalanche energ | у          | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 19 A, L = 1 mH  |   | 180    | mJ    |
| Repetitive avalanche current   |            | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical |   | 40     | А     |

| ELECTRICAL SPECIFICATIONS       |                  |  |                                       |                            |       |
|---------------------------------|------------------|--|---------------------------------------|----------------------------|-------|
| PARAMETER                       | SYMBOL           | TEST CONDITIONS  |                                       | VALUES                     | UNITS |
|                                 |                  | 200 A  | T <sub>J</sub> = 25 °C                | 0.67                       | V     |
| Maximum forward voltage drop    |                  | 400 A  |                                       | 0.92                       |       |
| waximum forward voltage drop    | $V_{FM}$         | 200 A  | T <sub>J</sub> = 125 °C               | 0.73                       | V     |
|                                 |                  | 400 A  |                                       | 1.14                       |       |
| Maximum rayaraa laakaga aurrant | I <sub>RM</sub>  | T <sub>J</sub> = 25 °C                                       | V <sub>R</sub> = Rated V <sub>R</sub> | 20                         | mA    |
| Maximum reverse leakage current |                  | T <sub>J</sub> = 125 °C                                      |                                       | 1.2                        | Α     |
| Maximum junction capacitance    | C <sub>T</sub>   | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C |                                       | 10 300                     | pF    |
| Typical series inductance       | L <sub>S</sub>   | Measured lead to lead 5 mm from package body                 |                                       | 5.0                        | nΗ    |
| Maximum voltage rate of change  | dV/dt            | Rated V <sub>R</sub>   |                                       | 10 000                     | V/µs  |
| Maximum RMS insulation voltage  | V <sub>INS</sub> | 50 Hz  |                                       | 3000 (1 min)<br>3600 (1 s) | V     |

| THERMAL - MECHANICAL SPECIFICATIONS                     |             |                                   |  |             |          |
|---|-------------|-----------------------------------|--|-------------|----------|
| PARAMETER   |             | SYMBOL                            | TEST CONDITIONS  | VALUES      | UNITS    |
| Maximum junction and storage temperature range          |             | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to +150 | °C       |
| Maximum thermal resistance, junction to case per leg    |             | $R_{thJC}$                        | DC operation   | 0.26        | °C/W     |
| Typical thermal resistance, case to heatsink per module |             | R <sub>thCS</sub>                 |  | 0.1         | C/VV     |
| Approximate weight                                      |             |                                   |  | 75          | g        |
| Approximate weight                                      |             |                                   |  | 2.7         | oz.      |
| Mounting torque ± 10 %                                  | to heatsink | (                                 | A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the | 4           | Nm       |
| busbar  |             |                                   | spread of the compound.  | 3           | INIII    |
| Case style  |             |                                   | JEDEC®   | TO-240AA co | mpatible |



10 000 150 °C I<sub>R</sub> - Reverse Current (mA) 1000 125 °C 100 °C 100 75 10 0.1 10 0 20 30 40 50 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

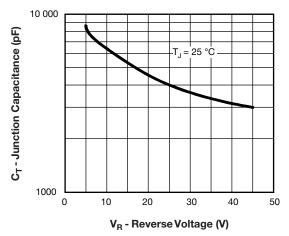


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

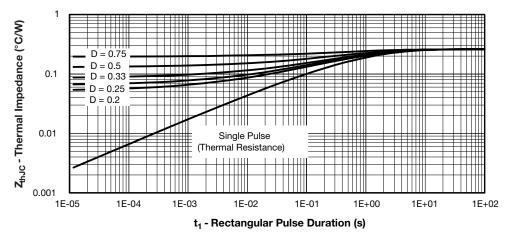


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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## Vishay Semiconductors

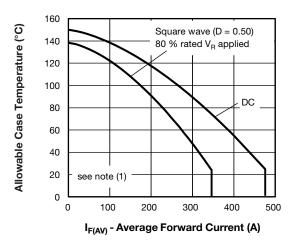


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

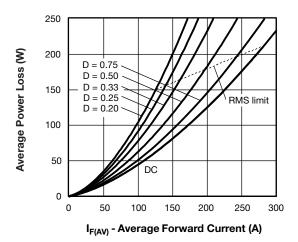
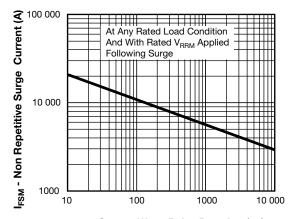


Fig. 6 - Forward Power Loss Characteristics



t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

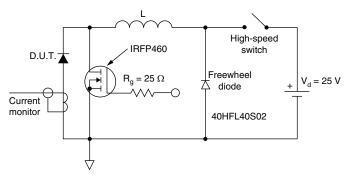


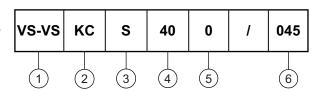
Fig. 8 - Unclamped Inductive Test Circuit

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80 \%$  rated  $V_R$ 

#### **ORDERING INFORMATION TABLE**

Device code



1 - VS-VS = Vishay Semiconductors product

2 - Circuit configuration:

KC = ADD-A-PAK - 2 diodes / common cathode

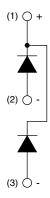
S = Schottky diode

4 - Average rating (x 10)

Product silicon identification

6 - Voltage rating (045 = 45 V)

#### **CIRCUIT CONFIGURATION**

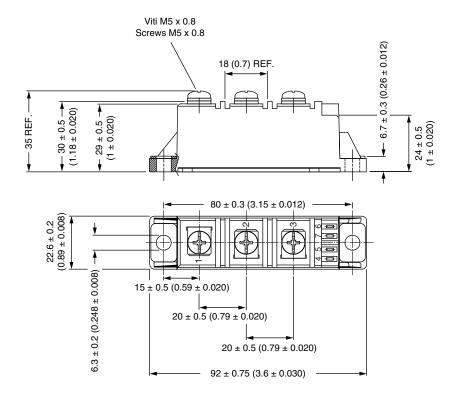


| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95369 |  |  |



# **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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